









	NSBC143ZPDXV6T1G	
	Hersteller-Teilenummer:	NSBC143ZPDXV6T1G
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	TRANS PREBIAS NPN/PNP SOT563
	Datenblätter:	 NSBC143ZPDXV6T1G.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 36000 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	NSBC143ZPDXV6T1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	TRANS PREBIAS NPN/PNP SOT563
Kategorie	Diskrete Halbleiterprodukte > Transistoren-bipolare
Teilstatus	36000 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Leistung - max	500mW
Verpackung / Gehäuse	SOT-563, SOT-666
Supplier Device-Gehäuse	SOT-563
Transistor-Typ	1 NPN, 1 PNP - Pre-Biased (Dual)
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	250mV @ 1mA, 10mA
Strom - Collector Cutoff (Max)	500nA
DC Stromgewinn (HFE) (Min) @ Ic, VCE	80 @ 5mA, 10V
Frequenz - Übergang	-
Widerstand - Base (R1) (Ohm)	4.7k
Widerstand - Emitter-Basis (R2) (Ohm)	47k
Verpackung	Tape & Reel (TR)

NSBC143ZPDXV6T1G ist neu im Original, Suche NSBC143ZPDXV6T1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NSBC143ZPDXV6T1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NSBC143ZPDXV6T1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NSBC143ZPDXV6T5G AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN/PNP SOT563</p>	 <p>NSBC144EDXV6T1G AMI Semiconductor / ON Semiconductor TRANS 2NPN PREBIAS 0.5W SOT563</p>	 <p>NSBC143ZDXV6T5G AMI Semiconductor / ON Semiconductor TRANS 2NPN PREBIAS 0.5W SOT563</p>	 <p>NSBC143ZF3T5G AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 254MW SOT1123</p>
 <p>NSBC143ZPDP6T5G AMI Semiconductor / ON Semiconductor TRANS 2NPN PREBIAS 0.339W SOT963</p>	 <p>NSBC143ZPDXV6T5 AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN/PNP SOT563</p>	 <p>NSBC143ZDXV6T1G AMI Semiconductor / ON Semiconductor TRANS 2NPN PREBIAS 0.5W SOT563</p>	 <p>NSBC143ZDXV6T1 AMI Semiconductor / ON Semiconductor TRANS 2NPN PREBIAS 0.5W SOT563</p>

heiße Teile

Mehr

0603ZC272KAT2A	AFT05MS004NT1	ESD8V0R1B-02LRHE6327	D GCM3195C2A432JA16D	K6T4008U1C-YF10
L03S200D15WM	MAX824REXK+T	D MCP102T-195I/LB	NSB1706DMW5T1G	NSB4904DW1T1G
NSB8JT-E3/31	NSB9435T1	NSB9435T1G	NSBA114EDP6T5G	NSBA114EDXV6T1
D NSBA114YDXV6T1	NSBA123JDXV6T1	NSBA123JDXV6T1G	NSBA123JDXV6T5G	NSBA143TDXV6T1G
NSBA144EDP6T5G	NSBC114EDXV6T1	NSBC114EDXV6T1G	NSBC114EPDXV6T1G	NSBC114EPDXV6T5
NSBC114TDXV6T1	NSBC114YDP6T5G	D NSBC114YDXV6T1	NSBC114YDXV6T1G	NSBC114YDXV6T5
NSBC114YPDXV6T1	D NSBC115EDXV6T1	NSBC123JDXV6T1	NSBC123JPDV6T1	NSBC123JPDV6T1G
NSBC124EPDXV6T1	NSBC124EPDXV6T5	NSBC124XPDXV6T1	NSBC143EDXV6T5	NSBC143ZPDXV6T5
NSBC144EDXV6T1	NSBC144EDXV6T1G	NSBC144EDXV6T5	D NSBC144EDXV6T5G	NSBC144EPDXV6T1
NSBC144EPDXV6T1G	SMF9.0A-GS08	SN74HC161N	TA20141803	VE-223-CY

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